onsemi

<u>Silicon Carbide Schottky</u> <u>Diode</u>

650 V, 6 A FFSD0665B-F085

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 24.5 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Automotive HEV-EV Onboard Chargers
- Automotive HEV-EV DC-DC Converters

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

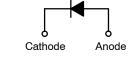
| Parameter | Symbol | Value | Unit | |
|---|---|------------------|------|----|
| Peak Repetitive Reverse Voltage | | V _{RRM} | 650 | V |
| Single Pulse Avalanche Energy (T_J = 25°C, $I_{L(pk)}$ = 9.9 A, L = 0.5 mH, V = 50 V) | | E _{AS} | 24.5 | mJ |
| Continuous Rectified Forward | T _C < 154 | ١ _F | 6.0 | А |
| Current | T _C < 135 | | 9.1 | |
| Non-Repetitive Peak Forward Surge Current | T _C = 25°C, t _P = 10 μs | I _{FM} | 493 | A |
| | $\begin{array}{l} T_C = 150^\circ C, \\ t_P = 10 \ \mu s \end{array}$ | | 442 | |
| Non-Repetitive Forward Surge Current (Half-Sine Pulse) | T _C = 25°C t _P = 8.3 ms | I _{FSM} | 28 | A |
| Power Dissipation | T _C = 25°C | P _{tot} | 75 | W |
| | T _C = 150°C | | 12.5 | |
| Operating Junction and Storage T Range | T _J , T _{stg} | –55 to +175 | °C | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

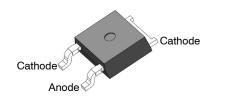
THERMAL RESISTANCE

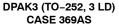
| Parameter | Symbol | Value | Unit |
|--------------------------------------|-----------------|-------|------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 2.0 | °C/W |

| V _{RRM} | ١ _F |
|------------------|----------------|
| 650 V | 6.0 A |
| | |
| | |

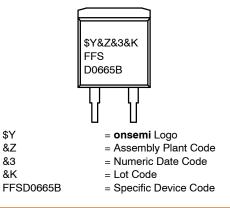


Schottky Diode





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSD0665B-F085

ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Unit |
|--------------------------------|---|--|------|------|-----|------|
| ON CHARAC | TERISTICS | | | | | |
| V _F Forward Voltage | $I_F = 6.0 \text{ A}, \text{ T}_J = 25^{\circ}\text{C}$ | | 1.38 | 1.7 | V | |
| | | I _F = 6.0 A, T _J = 125°C | | 1.53 | 2.0 | |
| | | I _F = 6.0 A, T _J = 175°C | | 1.67 | 2.4 | |
| I _R Reverse Current | $V_{R} = 650 \text{ V}, \text{ T}_{J} = 25^{\circ}\text{C}$ | | 0.5 | 40 | μΑ | |
| | | V_{R} = 650 V, T _J = 125°C | | 1.0 | 80 | |
| | | V _R = 650 V, T _J = 175°C | | 2.0 | 160 | |

CHARGES, CAPACITANCES & GATE RESISTANCE

| Q _C | Total Capacitive Charge | V _C = 400 V | 16 | nC |
|------------------|-------------------------|-------------------------------------|-----|----|
| C _{tot} | | V _R = 1 V, f = 100 kHz | 259 | pF |
| | | V _R = 200 V, f = 100 kHz | 29 | |
| | | V _R = 400 V, f = 100 kHz | 22 | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

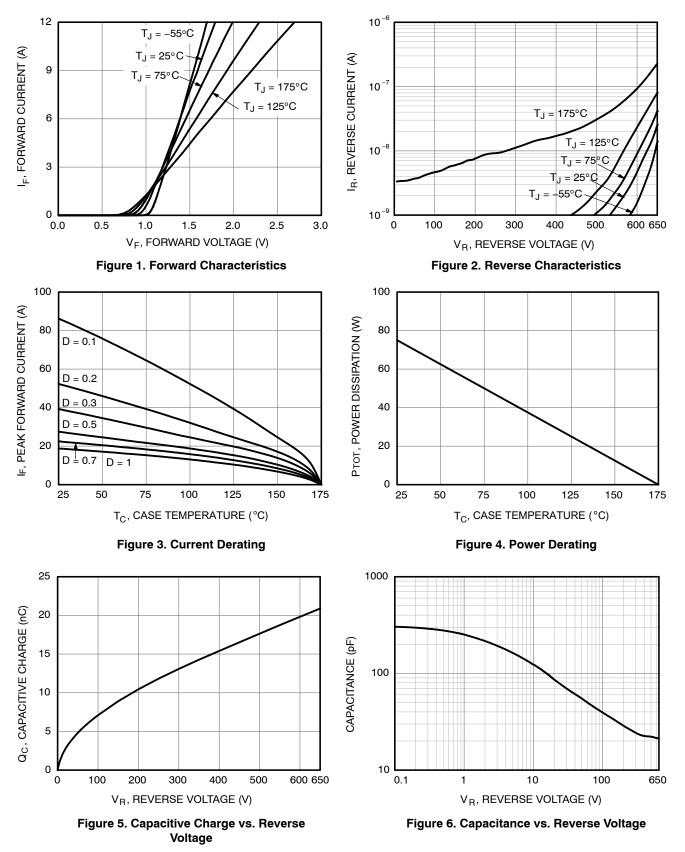
PART MARKING AND ORDERING INFORMATION

| Part Number | Top Mark | Package | Packing Method [†] | Reel Size | Tape Width | Quantity |
|----------------|-----------|---------|-----------------------------|-----------|------------|------------|
| FFSD0665B-F085 | FFSD0665B | DPAK | Tape & Reel | 330 mm | 16 mm | 2500 units |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

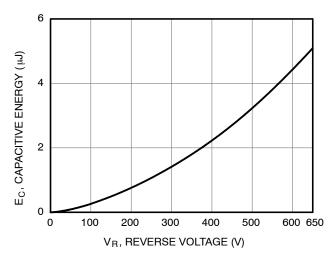
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TYPICAL CHARACTERISTICS



FFSD0665B-F085

TYPICAL CHARACTERISTICS





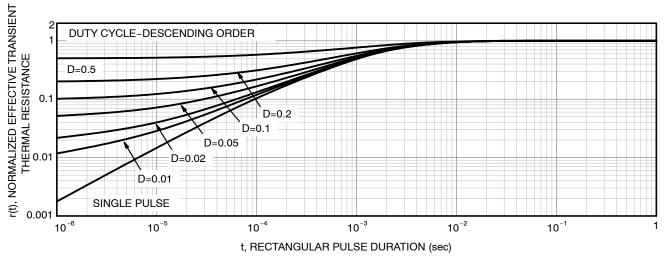
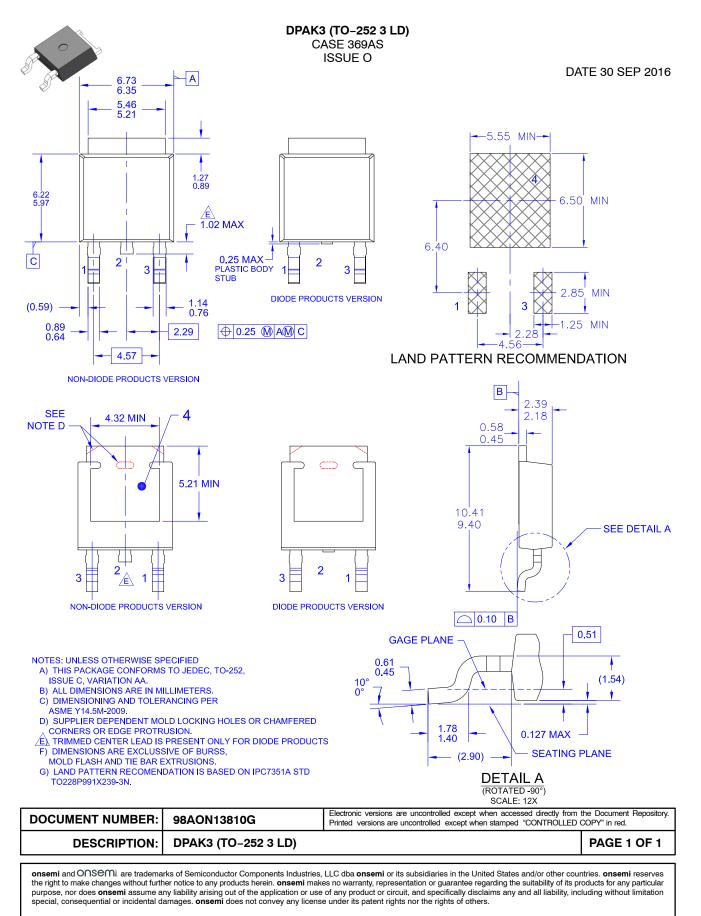


Figure 8. Junction-to-Case Transient Thermal Response

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



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